

Features

- AEC-Q101 Qualified
- Trench Power LV MOSFET technology
- Halogen Free. "Green" Device (Note 1)
- · Excellent Package for Good Heat Dissipation
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

Operating Junction Temperature Range : -55°C to +150°C

Storage Temperature Range: -55°C to +150°C

• Thermal Resistance: 50°C/W Junction to Ambient(Note 2)

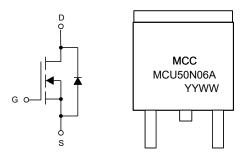
• Thermal Resistance: 2.1°C/W Junction to Case

Parameter		Symbol	Rating	Unit	
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Volltage		V _{GS}	±20	V	
Continuous Drain Current	T _C =25°C	. I _D	50	Α	
	T _C =100°C	'D	32		
Pulsed Drain Current(Note 3)		I _{DM}	120	Α	
Total Power Dissipation(Note 4)		P _D	59.5	W	
Single Pulse Avalanche Energy ^(Note 5)		E _{AS}	72	mJ	

Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C. The Power dissipation P_{DSM} is based on $R_{\theta JA}$ t≤ 10s and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. $\mbox{P}_{\mbox{\scriptsize D}}$ is based on max. junction temperature, using junction-case thermal resistance.
- 5. T_J =25°C, V_{DD} = 50V, V_{GS} = 10V, L= 0.5mH.

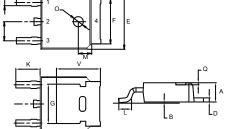
±bhYfbU `Ghfi WhifY`UbX`A Wf_]b['7cXY



4 codes in total YY is the year WW is the week

N-CHANNEL MOSFET





- 1. Gate
- 2,4. Drain
 - 3. Source

DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	NOTE
Α	0.087	0.094	2.20	2.40	
В	0.000	0.005	0.00	0.13	
С	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
Е	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
Н	0.236	0.244	6.00	6.20	
	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
K	0.1	14	2.9	90	TYP.
L	0.055	0.067	1.40	1.70	
М	0.063		1.60		TYP.
0	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.35		TYP.

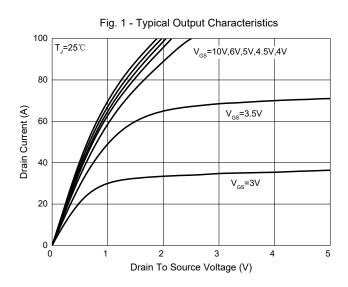


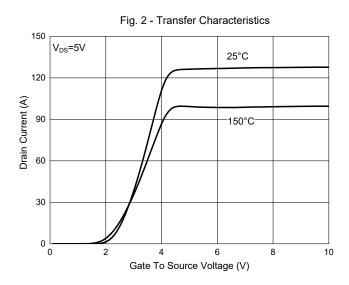
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

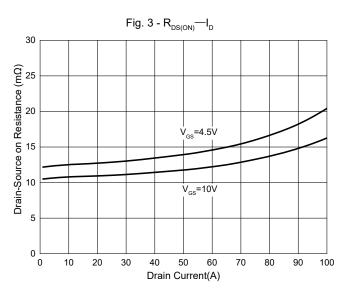
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics	-			1	I	1	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} =0V, I_{D} =250 μ A	60			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1	μΑ	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.5	2.5	V	
Drain-Source On-Resistance		V _{GS} =10V, I _D =15A		11	15	m0	
	$R_{DS(on)}$	V _{GS} =4.5V, I _D =10A	12.5		18	mΩ	
Gate Resistance	R_g	F=1 MHz, Open drain		1.2		Ω	
Drain-Source Body Diode Ch	aracteristi	cs					
Continuous Body Diode Current	Is			50		Α	
Diode Forward Voltage	V _{SD}	I _S =15A, V _{GS} =0V		0.85	1.2	V	
Reverse Recovery Time	t _{rr}				32	nS	
Reverse Recovery Charge	Q _{rr}	I_{DS} =20A, d _i /d _t =100A/ μ s			28.2	nC	
Dynamic Characteristics							
Input Capacitance	C _{iss}			2515			
Output Capacitance	C _{oss}	V_{DS} =25V, V_{GS} =0V,f=1MHz		165		pF	
Reverse Transfer Capacitance	C _{rss}			130			
Total Gate Charge	Qg			46			
Gate-Source Charge	Q _{gs}	V_{DD} =30V, V_{GS} =10V, I_{D} =20A		6		nC	
Gate-Drain Charge	Q_{gd}			11			
Turn-On Delay Time	t _{d(on)}			9			
Turn-On Rise Time	t _r	$V_{DD} = 30V, V_{G} = 10V,$		41			
Turn-Off Delay Time	t _{d(off)}	I _{DS} =20A		28		- ns	
Turn-Off Fall Time	t _f			2.8			

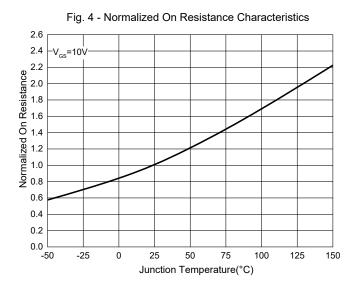


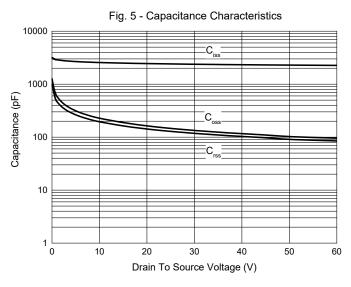
Curve Characteristics

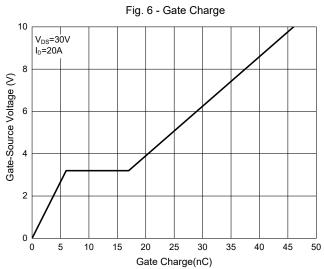






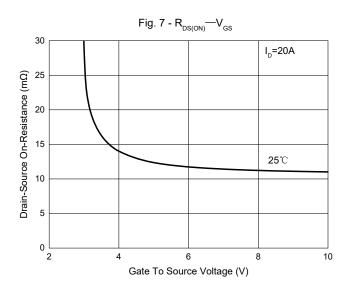


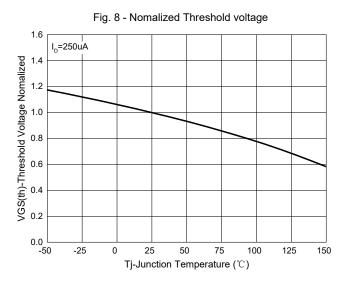


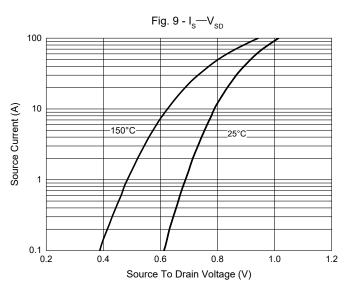


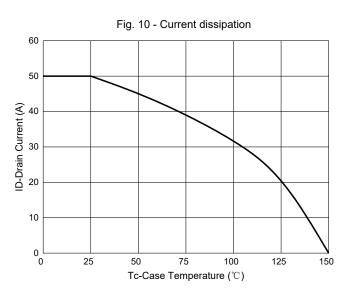


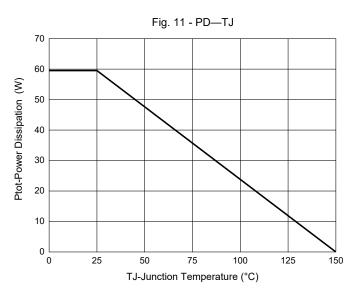
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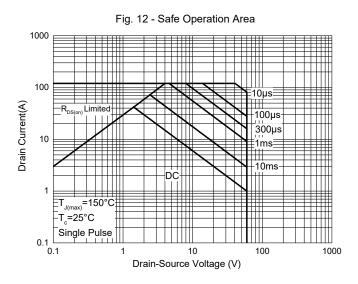


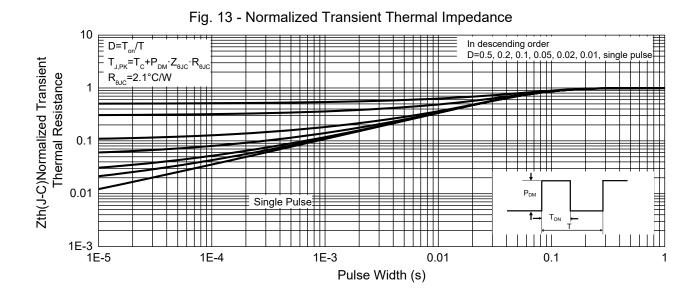






Curve Characteristics





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Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

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